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DLS 061

## 3 Amp Schottky Barrier Rectifiers

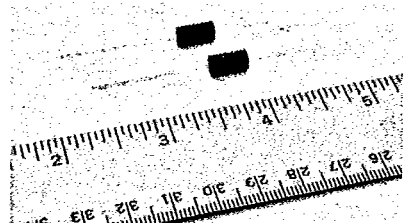
January 1990

20 Volt, 30 Volt and 40 Volt  $V_{RRM}$

.475 Volt  $v_F$  at  $i_F = 3.0$  Amp

Very Fast Recovery Time

Minimum Sized, Low Cost Epoxy Encapsulation

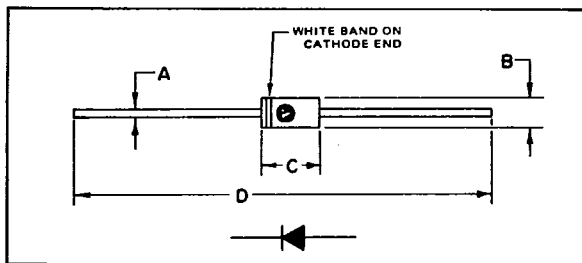


| MAXIMUM RATINGS<br>(At $T_A = 25^\circ\text{C}$ unless otherwise noted)  | SYMBOL       | VSK320       | VSK330 | VSK340 | UNITS            |
|--------------------------------------------------------------------------|--------------|--------------|--------|--------|------------------|
| DC Blocking Voltage                                                      | $V_{RM}$     | 20           | 30     | 40     | Volts            |
| Working Peak Reverse Voltage                                             | $V_{RWM}$    |              |        |        |                  |
| Peak Repetitive Reverse Voltage                                          | $V_{RRM}$    |              |        |        |                  |
| RMS Reverse Voltage                                                      | $V_{R(RMS)}$ | 14           | 21     | 28     | Volts            |
| Average Rectified Forward Current (Fig. 5 & 6)                           | $I_o$        | 3.0          |        |        | Amps             |
| Ambient Temp. @ Rated $V_{RM}$ , $R_{\theta JA} \leq 24^\circ\text{C/W}$ | $T_A$        | 85           | 80     | 75     | $^\circ\text{C}$ |
| Peak Surge Current (non-rep), 300 $\mu\text{s}$ Pulse Width (Fig. 4)     | $I_{FSM}$    | 250          |        |        | Amps             |
| Peak Surge Current (non-rep), $\frac{1}{2}$ cycle, 60Hz (Fig. 4)         | $I_{FSM}$    | 150          |        |        | Amps             |
| Operating Junction Temperature                                           | $T_J$        | -65 to +150* |        |        | $^\circ\text{C}$ |
| Storage Temperature                                                      | $T_{STG}$    | -65 to +150  |        |        | $^\circ\text{C}$ |

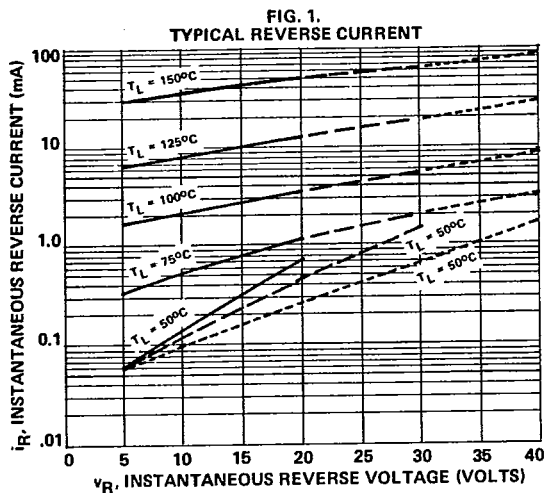
\*  $V_{RM} \leq 0.1 V_{RM}$  Max,  $R_{\theta JA} \leq 32^\circ\text{C/W}$

| ELECTRICAL CHARACTERISTICS<br>(At $T_A = 25^\circ\text{C}$ unless otherwise noted)                                                                      | SYMBOL | VSK320               | VSK330 | VSK340 | UNITS |
|---------------------------------------------------------------------------------------------------------------------------------------------------------|--------|----------------------|--------|--------|-------|
| Maximum Instantaneous Forward Voltage Drop (1)<br>See Fig. 2 for Typical $v_F$<br>$i_F = 1.0$ Amp<br>$i_F = 3.0$ Amps<br>$i_F = 10.0$ Amps              | $v_F$  | .400<br>.475<br>.750 |        |        | Volts |
| Maximum Instantaneous Reverse Current<br>at Rated $V_{RM}$ (1)<br>See Fig. 1 for Typical $i_R$<br>$T_L = 25^\circ\text{C}$<br>$T_L = 100^\circ\text{C}$ | $i_R$  | 3.0<br>30.0          |        |        | mA    |

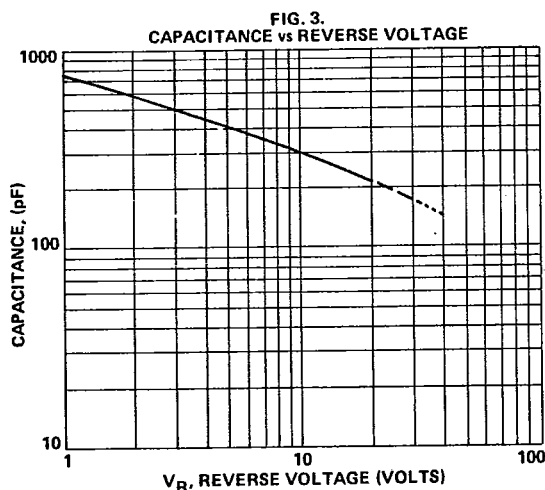
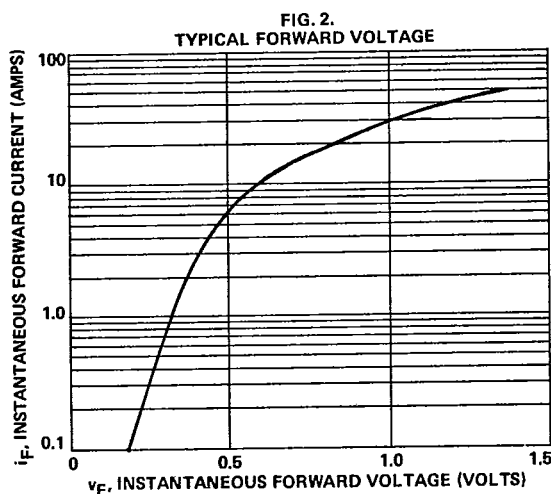
(1) Pulse Test: Pulse Width = 300  $\mu\text{s}$ , Duty Cycle = 2%



| LTR. | INCHES           | MILLIMETERS      |
|------|------------------|------------------|
| A    | .048 — .052 Dia. | 1.22 — 1.32 Dia. |
| B    | .190 — .225      | 4.83 — 5.72      |
| C    | .370 — .390      | 9.40 — 9.91      |
| D    | 2.75             | 69.85            |



$T_L$  = LEAD TEMP. MEASURED  
 .03"—.79mm FROM  
 RECTIFIER BODY WITH  
 40 GAUGE THERMOCOUPLE

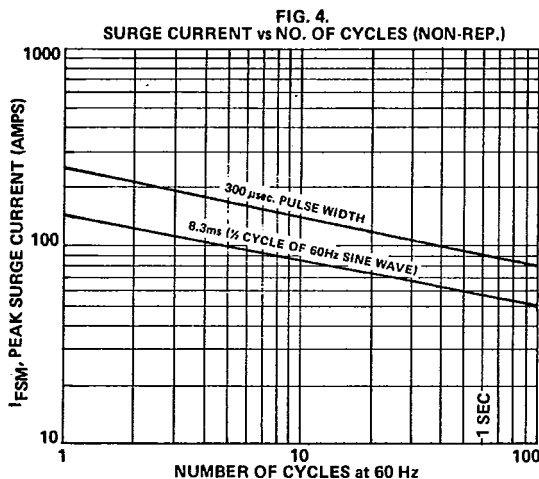


The current flow in a Schottky barrier rectifier is due to majority carrier conduction and is not affected by reverse recovery transients due to stored charge and minority carrier injection as in conventional PN diodes.

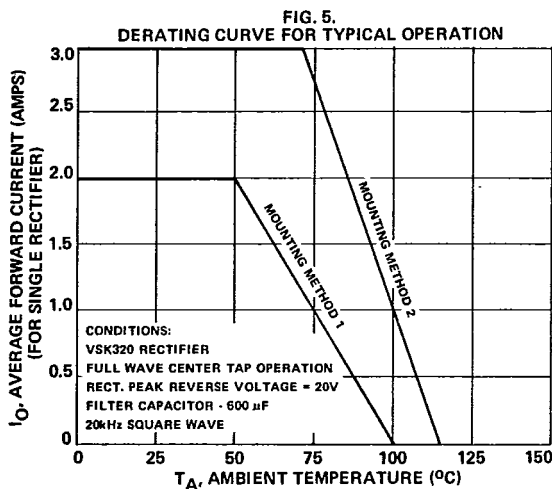
The Schottky barrier rectifier may be considered for purposes of circuit analysis, as an ideal diode in parallel with a variable capacitance equal in value to the junction capacitance. See Figure 3.

# 3 Amp Schottky Barrier Rectifiers

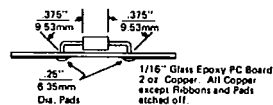
7-20



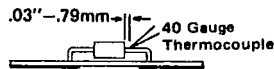
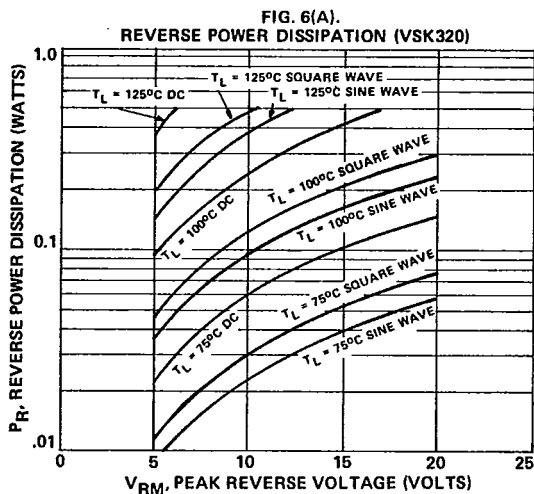
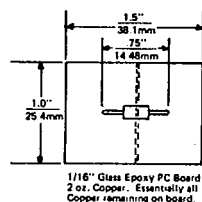
$$T_A = 25^\circ\text{C}$$



## MOUNTING METHOD 1



## MOUNTING METHOD 2 - TOP VIEW



REVERSE POWER MULTIPLIES 1.32x FOR EACH  $5^\circ\text{C}$  TEMP. INCREASE.

USE THIS MULTIPLIER FOR INTERPOLATION BETWEEN CURVES SHOWN ON FIGURES 6(A), 6(B), 6(C),

USE  $75^\circ\text{C}$  CURVES FOR ALL CASE TEMP. BELOW  $75^\circ\text{C}$ .

FIG. 6(B)

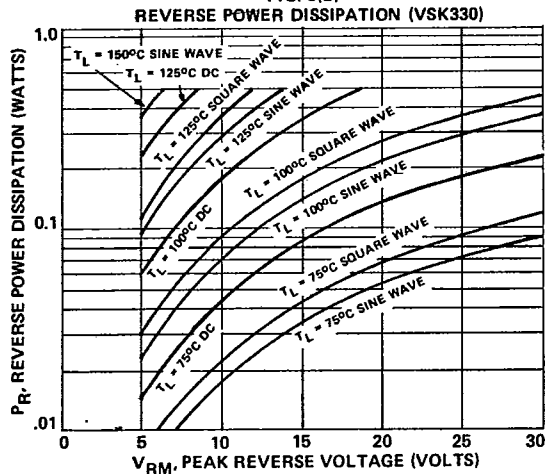


FIG. 6(C)

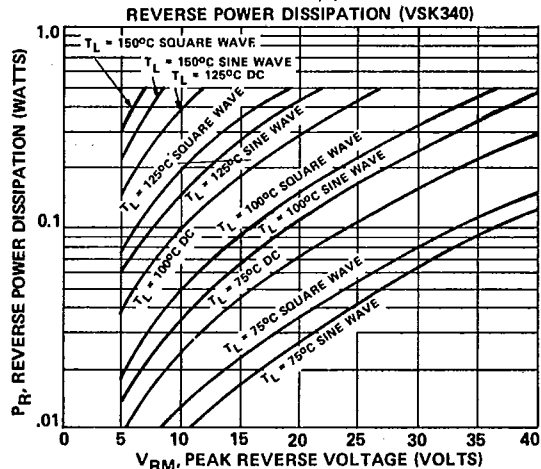


FIG. 6(D)  
**FORWARD POWER DISSIPATION  
VSK320, VSK330, VSK340**

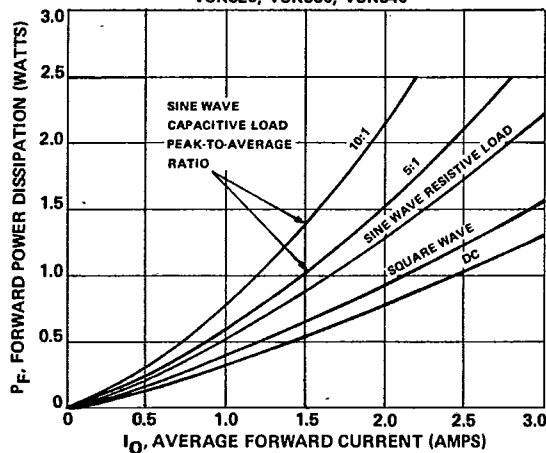
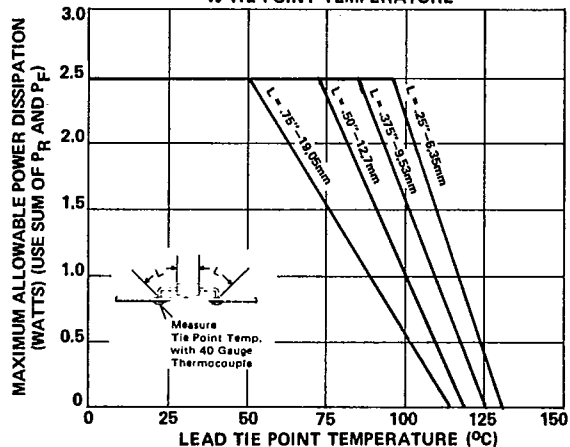


FIG. 6(E)  
**MAXIMUM ALLOWABLE POWER DISSIPATION  
vs TIE POINT TEMPERATURE**



#### Thermal Considerations:

1. The derating curve of figure 5 may be used for initial design work.
2. Use the curves of figure 6 to study the voltage / current / temperature parameters. These curves are helpful in determining the rectifier capability when connected to a tie point whose temperature is influenced by other heat producing components. To use these curves, add the reverse power dissipation from figure 6 (A), (B) or (C) to the forward power dissipation from figure 6 (D) then go to figure 6 (E) to find the maximum allowable tie point temperature.
3. The heat sink design (tie point) must be designed to keep the temperature at this point below that shown on the figure 6 (E) curve. Thermal runaway is entirely possible on marginal designs due to the inherently large reverse leakage of Schottky barrier rectifiers and the fact that reverse power multiplies about 1.32 times for each 5° C of temperature increase.
4. The curves of figure 6 (E) were based on full rated reverse bias voltage. Slightly higher tie point temperatures can be tolerated at lower voltages. We recommend that all designs be verified at an ambient temperature at least 10° C higher than the maximum at which the equipment will ever have to operate.
5. If the application is such that DC reverse bias is applied nearly 100% of the time, all temperature points on curve 6 (E) should be reduced 13° C.
6. These thermal resistances apply:  $R_{\theta JL}$  (measured 1/32" from epoxy) = 6° C/W and the lead = 25° C/W per inch when equal heatsinking is applied to each lead.